

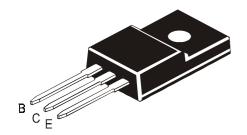
### Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer



### PNP SILICON PLANAR DARLINGTON POWER TRANSISTOR

**CJF6668** 



TO-220FP Fully Isolated Plastic Package

### **Complementary CJF6388**

### **General Purpose Darlington Amplifier and Switching Applications**

### ABSOLUTE MAXIMUM RATINGS

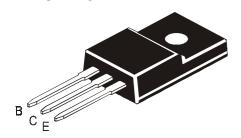
DESCRIPTION	SYMBOL	VALUE	UNIT	
Collector Base Voltage	$V_{ ext{CBO}}$	100	V	
Collector Emitter Voltage	$V_{CEO}$	100	V	
Emitter Base Voltage	$V_{EBO}$	5	V	
RMS Isolation Voltage (for 1sec,R.H.	(1) V <sub>ISOL</sub> (a)	3500	$V_{RMS}$	
<30%, T <sub>A</sub> =25°C )	(b)	1500	$V_{RMS}$	
Collector Current - Continuous	$I_{C}$	10	Α	
Peak (2)		15	Α	
Base Current	$I_{B}$	1	Α	
Total Power Dissipation @ Tc=25°C	$P_{D^{**}}$	40	W	
Derate Above 25°C		0.31	W/°C	
Total Power Dissipation @ Ta=25°C	$P_{D}$	2	W	
Derate Above 25°C		0.016	W/°C	
Operating and Storage Junction	$T_{i}T_{stq}$	- 65 to +150	°C	
Temperature Range	, -			
THERMAL RESISTANCE				
From Junction to Case	$R_{th (j-c)^{**}}$	3.2	°C/W	
From Junction to Ambient	$R_{\text{th (j-a)}}$	62.5	°C/W	
Lead Temperature for Soldering Purpose	$T_L$	260	°C	

<sup>\*\*</sup>Measurement made with thermocouple contacting the bottom insulated mounting surface (in a location beneath the die), the device mounted on a heatsink with thermal grease and a mounting torque of ≥6 in.lbs.

(2) Pulse Test : Pulse Width =5ms, Duty Cycle<10%

<sup>(1)</sup> RMS Isolation Voltage : (a) 3500 V<sub>RMS</sub> with Package in Clip Mounting Position (b) 1500 V<sub>RMS</sub> with Package in Screw Mounting Position (for 1sec, R.H.<30% ,Ta=25°C; Pulse Test: Pulse Width ≤300μs, Duty Cycle≤2%)





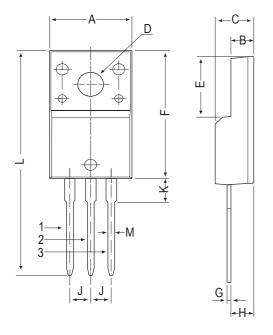
## ELECTRICAL CHARACTERISTICS (Tc=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter sustaining Voltage Collector Cut off Current	V <sub>CEO (sus)</sub> * I <sub>CEO</sub> I <sub>CEX</sub>	$I_{C}$ =30mA, $I_{B}$ =0 $V_{CE}$ =80V, $I_{B}$ =0 $V_{CE}$ =100V, $V_{EB}$ (off)=1.5V	100	10 10	V μΑ μΑ
Emitter Cut off Current DC Current Gain		$T_{C}$ =125°C $V_{CE}$ =100V, $V_{EB}$ (off)=1.5V $V_{CB}$ =100V, $I_{E}$ =0 $V_{EB}$ =5V, $I_{C}$ =0 $I_{C}$ =3A, $V_{CE}$ =4V $I_{C}$ =5A, $V_{CE}$ =3V $I_{C}$ =8A, $V_{CE}$ =4V	3000 1000 200	3 10 2 15000	mA μA mA
Collector Emitter Saturation Voltage	V <sub>CE(Sat)</sub> *	$I_{C}$ =10A, $V_{CE}$ =3V $I_{C}$ =3A, $I_{B}$ =6mA $I_{C}$ =5A, $I_{B}$ =0.01A $I_{C}$ =8A, $I_{B}$ =80mA $I_{C}$ =10A, $I_{B}$ =0.1A	100	2 2 2.5 3	V V V
Base Emitter Saturation Voltage	$V_{\text{BE(Sat)}}^{}$ *	I <sub>C</sub> =10A, I <sub>B</sub> =0.1A I <sub>C</sub> =5A, I <sub>B</sub> =0.01A I <sub>C</sub> =10A, I <sub>B</sub> =0.1A		2.8 4.5	V V
Base Emitter on Voltage	V <sub>BE(on)</sub> *	$I_C=8A$ , $V_{CE}=4V$		2.5	V
DYNAMIC CHARACTERISTICS					
Small Signal Current Gain Output Capacitance Small Signal Current Gain	Ih <sub>fe</sub> l C <sub>ob</sub> h <sub>fe</sub>	$I_{C}$ =1A, $V_{CE}$ =5V, f=1MHz $V_{CB}$ =10V, $I_{E}$ =0, f=1MHz $I_{C}$ =1A, $V_{CE}$ =5V, f=1kHz	20 1000	300	pF

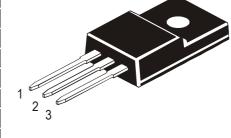
<sup>\*</sup> Pulse Test: Pulse Width ≤300µs, Duty Cycle ≤2 %

# TO-220FP Fully Isolated Plastic Package

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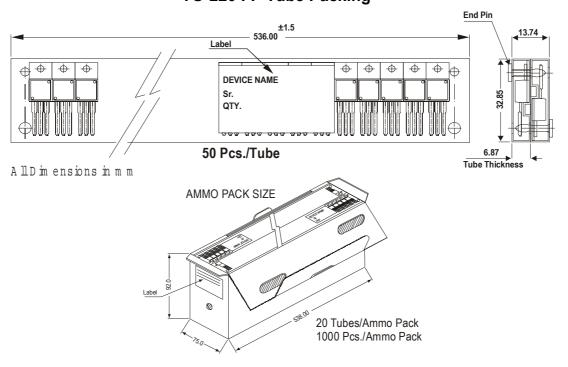
DIM	MIN	MAX			
Α	9.96	10.36			
В	2.60	3.00			
С	4.50	4.90			
D	3.10	3.30			
E	7.90	8.20			
F	16.87	17.27			
G	0.45	0.50			
Н	2.56	2.96			
J	2.34	2.74			
K	_	3.08			
L	_	30.05			
М	_	0.80			
All diminsions in mm.					



Pin Configuration

- 1. Base
- 2. Collector
- 3. Emitter

## **TO-220 FP Tube Packing**



# **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-220FP		396 gm/200 pcs 135 gm/50 pcs	3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"		17" x 15" x 13.5" 19" x 19" x 19"	16K 10K	36 kgs 28 kgs

Notes CJF6668

TO-220FP Fully Isolated Plastic Package

### **Disclaimer**

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